

AOZ8251BDI

One-line Bi-directional TVS Diode

General Description

The AOZ8251BDI is a one-line bi-directional transient voltage suppressor diode designed to protect voltage sensitive electronics from high transient conditions and ESD.

This device incorporates bi-directional TVS diode in an ultra-small DFN 1006 package. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge).

The AOZ8251BDI comes in an RoHS compliant DFN 1.0 mm x 0.6 mm package and is rated over a -40°C to +125°C ambient temperature range.

The ultra-small 0.62 mm x 0.32 mm x 0.5 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

- ESD protection for high-speed data lines
 - AOZ8251BDI-05:
 - Exceeds: IEC 61000-4-2 (ESD) ± 20 kV (air), ±20 kV (contact)
 - Human Body Model (HBM) ± 30 kV
 - IEC 61000-4-5 (Lightning) 4 A (8/20 μs)

AOZ8251BDI-12:

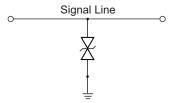
- Exceeds: IEC 61000-4-2 (ESD) ± 20 kV (air),± 20 kV (contact)
- Human Body Model (HBM) ± 30 kV
- IEC 61000-4-5 (Lightning) 1.5 A (8/20 μs)
- Pb-free device

Applications

- Portable hand-held devices
- Keypads, data lines, buttons
- Notebook computers
- Digital cameras
- Portable GPS



Typical Application



Bidirection Protection of Single Line

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental		
AOZ8251BDI-05	-40°C to +125°C	DFN 0.62 x 0.32	Green Product		
AOZ8251BDI-12	-40 C to +123 C				



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

	Rating for AOZ8251BDI		
Parameter	-05	-12	
VP – VN	5 V	12 V	
Peak Pulse Current, t _P = 8/20 μs	4 A	1.5 A	
Storage Temperature (T _S)	-65°C to +150°C		
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	± 20 kV	± 20 kV	
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	± 20 kV	± 20 kV	
ESD Rating per Human Body Model ⁽²⁾	± 30 kV	± 30 kV	

Notes:

- 1. IEC 61000-4-2 discharge with C_Discharge = 150 pF, R_Discharge = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100 pF, $R_{Discharge}$ = 1.5 k Ω .

Maximum Operating Ratings

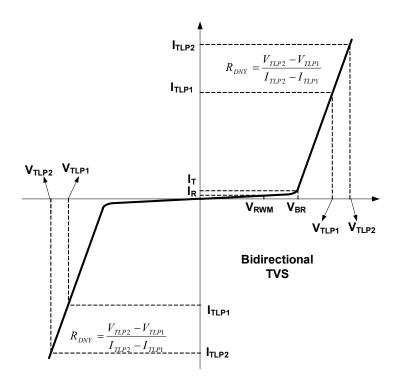
Parameter	Rating		
Junction Temperature (T _J)	-40°C to +125°C		

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Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.



AOZ8251BDI-05						
Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	I/O Pin-to-Ground			5	V
V _{BR}	Reverse Breakdown Voltage	I _T =1mA, I/O Pin-to-Ground	5.5	6	8	V
I _R	Reverse Leakage Current	V _{RWM} =5V, I/O Pin-to-Ground		1	100	nA
	Clamping Voltage ⁽³⁾ (100ns Transmission Line Pulse, I/O Pin-to-Ground)	I _{TLP} =1A		8	11	V
V _{CL}		I _{TLP} =16A		16.5	24	V
	Clamping Voltage ⁽³⁾ (IEC61000-4-5, 8/20µs, I/O Pin-to-Ground)	I _{PP} =4A		15	18	V
R _{DNY}	Dynamic Resistance ⁽³⁾	I _{TLP} =1A to 12A		0.55		Ω
CJ	Junction Capacitance	V _{I/O} =0V, f=1MHz, I/O Pin-to-Ground		5	6.5	pF

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Electrical Characteristics (continued)

AOZ8251BDI-12						
Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	I/O Pin-to-Ground			12	V
V _{BR}	Reverse Breakdown Voltage	I _T =1mA, I/O Pin-to-Ground	13	14.5	16	V
I _R	Reverse Leakage Current	V _{RWM} =12V, I/O Pin-to-Ground		1	100	nA
	Clamping Voltage ⁽³⁾ (100ns Transmission Line Pulse, I/O Pin-to-Ground)	I _{TLP} =1A		18	20	V
V _{CL}		I _{TLP} =16A		25	33	V
	Clamping Voltage ⁽³⁾ (IEC61000-4-5, 8/20µs, I/O Pin-to-Ground)	I _{PP} =1.5A			25	V
R _{DNY}	Dynamic Resistance ⁽³⁾	I _{TLP} =10A to 20A		0.3		Ω
CJ	Junction Capacitance	V _{I/O} =0V, f=1MHz, I/O Pin-to-Ground		4.5	6.5	pF

Note:

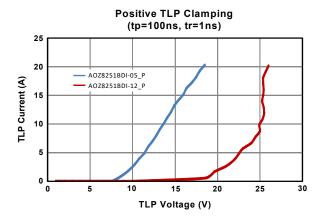
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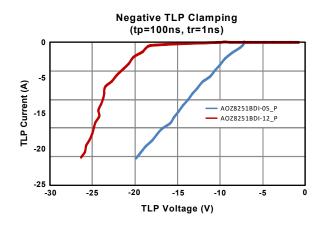
 $[\]ensuremath{\mathtt{3}}.$ These specifications are guaranteed by design and characterization.

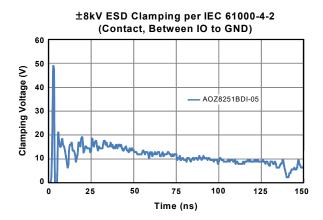


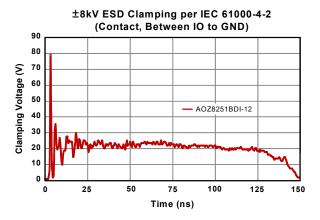
Typical Performance Characteristics

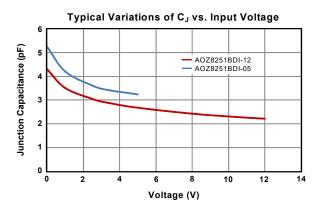
 $T_A = 25$ °C, unless otherwise specified.











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- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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